

Description

The FDY100PZ uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

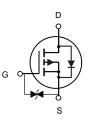
 $V_{DS} = -20V I_D = -0.66A$ $R_{DS(ON)} < 560 m\Omega@ V_{GS} = -4.5V$ $R_{DS(ON)} < 780 m\Omega@ V_{GS} = -2.5V$ ESD Rating: 1500V HBM

Application

Battery protection Load switch Uninterruptible power supply







P-Channel MOSFET

Package Marking and Ordering Information

<u> </u>				
Product ID	Pack	Brand	Qty(PCS)	
FDY100PZ	SOT-523	HXY MOSFET	3000	

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Symbol	Parameter	Limit	Unit
Vds	Drain-Source Voltage	-20	V
Vgs	Gate-Source Voltage	±12	V
ID	Drain Current-Continuous	-0.66	А
P _D	Maximum Power Dissipation	150	mW
Тј,Тѕтб	Operating Junction and Storage Temperature Range	-55 To 150	°C
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	833	°C /W



Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
STATIC CHARACTERISTICE						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250µA	-20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-20V,V _{GS} = 0V			-1	μA
Gate-body leakage current	lgss	V _{GS} =±10V, V _{DS} = 0V			±10	μA
Gate threshold voltage (note2)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250µA	-0.4	-0.7	-1.0	V
	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.5A			0.56	Ω
Drain-source on-resistance (note2)		V _{GS} =-2.5V, I _D =-0.2A			0.78	Ω
Maximum Continuous Drain to Source Diode Forward Current	ls				-0.6	A
Maximum Pulsed Drain to Source Diode Forward Current	Іѕм				-1.2	A
Diode forward voltage	V _{SD}	I _S =-0.5A, V _{GS} = 0V			-1.2	V
DYNAMIC CHARACTERISTICS (note4)						
Input capacitance	C _{iss}			115		pF
Output capacitance	Coss	V _{DS} =-16V,V _{GS} =0V, f =1MHz		15		pF
Reverse transfer capacitance	C _{rss}			9		pF
	te4)					
Turn-on delay time (note3)	t _{d(on)}			9		nS
Turn-on rise time (note3)	tr	V _{GS} =-4.5V,V _{DS} =-10V,		6		nS
Turn-off delay time (note3)	$t_{d(off)}$	I_D =-200mA,R _{GEN} =10 Ω		33		nS
Turn-off fall time (note3)	t _f			22		nS

Electrical Characteristics (TJ=25°C, unless otherwise noted)

Notes:

1. Surface mounted on FR4 board using the minimum recommended pad size.

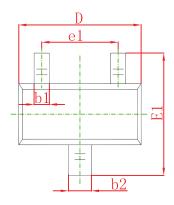
2. Pulse Test : Pulse Width=300µs, Duty Cycle=2%.

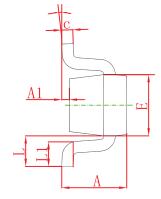
3. Switching characteristics are independent of operating junction temperatures.

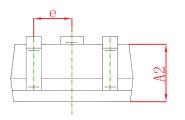
4. Guaranteed by design, not subject to producting.



SOT-523 Package Information

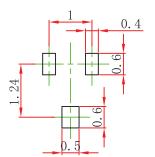






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
E	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

SOT-523 Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.



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